Solutions of

Electronics Engineering $\mathbf{FATE} = \mathbf{2016}$

Session 4 Set-3



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GATE 2016 : Solutions

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Mr. B. Singh

(Ex. IES) CMD, MADE EASY Group

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	One Mark Questions	
Q.1	 An apple costs ₹ 10. An onion costs ₹ 8. Select the most suitable sentence with respect to grammat (a) The price of an apple is greater than an onion. (b) The price of an apple is more than onion. (c) The price of an apple is greater than of an onion. (d) Apples are more costlier than onions. 	r and usage.
Ans.	(c)	
		End of Soluti
Q.2	The Buddha said, "Holding on to anger is like <u>grasping</u> a hot of throwing it at someone else; you are the one who gets b	coal with the inter ournt."
	Select the word below which is closest in meaning to the word	l underlined abov
	(a) burning (b) igniting	
	(c) clutching (d) flinging	
Ans.	(c)	
		- • • • End of Soluti
	P and daughter-in-law of M. How is P related to M?	
	 (a) P is the son-in-law of M (b) P is the grandchild of M (c) P is the daughter-in law of M (d) P is the grandfather of M 	
Ans.	 (a) P is the son-in-law of M (b) P is the grandchild of M (c) P is the daughter-in law of M (d) P is the grandfather of M (b) 	
Ans.	 (a) P is the son-in-law of M (b) P is the grandchild of M (c) P is the daughter-in law of M (d) P is the grandfather of M (b) 	– • • • End of Soluti
Ans. Q.4	 (a) P is the son-in-law of M (b) P is the grandchild of M (c) P is the daughter-in law of M (d) P is the grandfather of M (b) The number that least fits this set: (324, 441, 97 and 64) is 	– • • End of Soluti
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Ans. Q.4 Ans.	 (a) P is the son-in-law of M (b) P is the grandchild of M (c) P is the daughter-in law of M (d) P is the grandfather of M (b) (b) (c) 97 (d) 64 (c) 97 (e) 97 (f) 64 	- • • End of Soluti
Ans. Q.4 Ans. Q.5	 (a) P is the son-in-law of M (b) P is the grandchild of M (c) P is the daughter-in law of M (d) P is the grandfather of M (b) (b) The number that least fits this set: (324, 441, 97 and 64) is (a) 324 (b) 441 (c) 97 (d) 64 (c) 97 is not a perfect square. It takes 10s and 15s, respectively, for two trains travelling at the period of the set of	- • • • End of Soluti
Ans. Q.4 Ans. Q.5	 (a) P is the son-in-law of M (b) P is the grandchild of M (c) P is the daughter-in law of M (d) P is the grandfather of M (b) (b) The number that least fits this set: (324, 441, 97 and 64) is (a) 324 (b) 441 (c) 97 (d) 64 (c) 97 is not a perfect square. It takes 10s and 15s, respectively, for two trains travelling at speeds to completely pass a telegraph post. The length of the and that of the second train is 150 m. The magnitude of the and that of the second train is 150 m. The magnitude of the and that of the second train is 150 m. The magnitude of the second train i	 End of Soluti End of Soluti End of Soluti t different constant first train is 120 in the





Required area = Area of $\triangle ABC$ + Area of trapezoid BCDO $= \frac{1}{2} \times 4 \times 6 + \frac{1}{2} \times (4 + 2.5) \times 1$ = 12 + 3.25 = 15.25 sq. units End of Solution A straight line is fit to a data set (ln x, y). This line intercepts the abscissa at ln x = 0.1 and has a slope of -0.02. What is the value of y at x = 5 from the fit? (a) - 0.030 (b) - 0.014 (c) 0.014 (d) 0.030 (a) Straight line equation y = mx + cm = slope = -0.02 $(\ln x, y)$ If ln = X, then set (x, y)0.1 0 y = mX + C $o = -0.02 \times 0.1 + C$ C = 0.002*.*.. y = mX + C $y = -0.02 \times \log x + C$ at x = 5 $y = -0.02 \times \log 5 + 0.002$ = -0.030 End of Solution

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Q.10

Ans.

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Section - II (Electronics Engineering)
One Mark Questions
Q1 Consider a 2 × 2 square matrix

$$A = \begin{bmatrix} \sigma & x \\ 0 & \sigma \end{bmatrix}$$
where x is unknown. If the eigenvalues of the matrix A are $(\sigma + j\omega)$ and $(\sigma - j\omega)$, then x is equal to
(a) $+j\omega$ (b) $-j\omega$
(c) $+\omega$ (c) $-\omega$ (d) $-\omega$
Ans. (d)

$$A = \begin{bmatrix} \sigma & x \\ 0 & \sigma \end{bmatrix}$$
Trace = sum of eigen values
 $2\sigma = \sigma + j\omega + \sigma - j\omega$
 $|A|$ = product of eigens
 $\sigma^2 - x\omega = (\sigma + j\omega)(\sigma - j\omega) = \sigma^2 + \omega^2$
which is possible only when $x = -\omega$
(2. For $f(z) = \frac{\sin(z)}{z^2}$, the residue of the pole at $z = 0$ is ______.
Ans. (1)
Residue of $\frac{\sin z}{z^2}$ = coefficient of $\frac{1}{z}$ in $\left\{ \frac{z - \frac{z^3}{2!} + \frac{z^5}{5!} - -- \right\}$
 $= 1$
(2. For by the probability of getting a "head" in a single toss of a biased coin is 0.3. The coin is tossed repeatedly till a "head" is obtained. If the tosses are independent, then the probability of getting "head" for the first time in the fifth toss is ______.
Ans. (0.072)
 $P(H) = 0.3$
 $P(T) = 0.7$
since all tosses are independent

so, probability of getting head for the first time in $5^{
m th}$ toss is

= P(T) P(T) P(T) P(T) P(H)

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 $= 0.7 \times 0.7 \times 0.7 \times 0.7 \times 0.3$ = 0.072End of Solution The integral $\int_{0}^{1} \frac{dx}{\sqrt{1-x}}$ is equal to _____. Q.4 Ans. (2) $\int_{0}^{1} \frac{1}{\sqrt{1-x}} dx = -2 \int_{0}^{1} \frac{1}{2\sqrt{1-x}} dx = -2 (\sqrt{1-x}) \Big|_{0}^{1}$ = -2(0-1) = 2End of Solution Q.5 Consider the first order initial value problem $y' = y + 2x - x^2$, y(0) = 1, $(0 \le x < \infty)$ with exact solution $y(x) = x^2 + e^x$. For x = 0.1, the percentage difference between the exact solution and the solution obtained using a single iteration of the secondorder Runge-Kutta method with step-size h = 0.1 is ____. (0.044)Ans. $y' = y + 2x - x^2$ Given that Exact solution is given by $y(x) = x^2 + e^x$ $\gamma(0.1) = (0.1)^2 + e^{0.1} = 1.115$ $\frac{dy}{dx} = y + 2x - x^2$ y(0) = 1, h = 0.1 $f(x, y) = y + 2x - x^2, y_0 = 1, x_0 = 0$ $k_1 = h f(x_0, y_0) = h (y_0 + 2x_0 - x_0^2)$ (i) = 0.1 (1 + 0 + 0) = 0.1(ii) $k_2 = h (f (x_0 + h, y_0 + k_1))$ $= h (y_0 + k_1 + 2 (x_0 + h) - (x_0 + h)^2)$ $= 0.1 (1 + 0.1 + 2(0 + 0.1) - (0 + 0.1)^2)$ = 0.1 (1 + 0.1 + 0.2 - 0.01) = 0.129 $k = \frac{k_1 + k_2}{2} = \frac{0.1 + 0.129}{2} = 0.1145$ (iii) $y_1 = y_0 + k = 1 + 0.1145 = 1.1145$ (iv) $x_1 = x_0 + h = 0 + 0.1 = 0.1$ error = exact value - approximate value = 1.115 - 1.1145 = 0.0005The percentage difference $= \frac{0.0005}{1.115} \times 100 = 0.044\%$ End of Solution

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9.6 Consider the signal
$$x(t) = \cos(6\pi t) + \sin(8\pi t)$$
, where t is in seconds. The Nyquist sampling rate (in samples/second) for the signal $y(t) = x(2t + 5)$ is (a) 12 (b) 16 (c) 13 (c) 13

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Q.8

Ans.

Q.9

Ans.

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A discrete-time signal $x[n] = \delta[n]$	-3] $+2\delta[n-5]$ has z-transform X(z). If
Y(z) = X(-z) is the z-transform of	another signal $y[n]$, then
(a) $y[n] = x[n]$	(b) $y[n] = x[-n]$
(c) $y[n] = -x[n]$	(d) $y[n] = -x[-n]$
Given, $x[n]$	$= \delta[n-3] + 2\delta[n-5]$
X(z)	$= z^{-3} + 2z^{-5}$
X(-z)	$= (-z)^{-3} + 2(-z)^{-5}$
Y(z)	$= X(-z) = -z^{-3} - 2z^{-5} = -[z^{-3} + 2z^{-5}]$
y[n]	= -x[n]
In the RLC circuit shown in the fig	gure, the input voltage is given by
$V_i(t) = 2\cos(200 t) + 4\sin(500 t)$	
The output voltage $V_0(t)$ is	
0.25 H 100 µF	
↑+ └── ₩ ───┘	↑+
	$_{0.4 \text{ H}} \bigotimes = 10 \mu \text{F}$
$V_i(t)$	$V_0(t)$
	$\mathbf{a}^{2\Omega}$
<u>y –</u>	¥ -
(a) $\cos(200t) + 2\sin(500t)$	(b) $2\cos(200t) + 4\sin(500t)$
(c) $\sin(200t) + 2\cos(500t)$	(d) $2\sin(200t) + 4\cos(500t)$
(b)	
0.25 H 100 uF	
	_
¶+	• • • • • • • • • •
2 Ω	
V(t)	
	$\mathbf{x}^{2}\Omega$
k	ð
Where, $V(t)$	$= 2\cos(200t) + 4\sin(500t)$
As different frequencies are operation	g using superposition theorem we get
for $\omega = 200$	g, using superposition theorem, we get
101 W - 200 Y	$= \omega L = (200) (0.25) = 50 \text{ O}$
Λ_L	$- \omega L - (200) (0.20) - 50.52$,
X_C	$=\frac{1}{\omega C}=\frac{1}{200 \times 100 \times 10^{-6}}=50 \ \Omega$
	ωC 200 × 100 × 10

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Q.10 The I-V characteristics of three types of diodes at the room temperature, made of semiconductors X, Y and Z, are shown in the figure. Assume that the diodes are uniformly doped and identical in all respects except their materials. If $E_{\sigma X}$, E_{gY} , and E_{gZ} are the band gaps of X, Y and Z, respectively, then



- (a) $E_{gX} > E_{gY} > E_{gZ}$ (b) $E_{gX} = E_{gY} = E_{gZ}$

- (c) $E_{gX}^{gA} < E_{gY}^{gA} < E_{gZ}^{gA}$ (d) no relationship among these band gaps exists



End of Solution

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_____emaced3y



Q.13 The diodes D1 and D2 in the figure are ideal and the capacitors are identical. The product RC is very large compared to the time period of the ac voltage. Assuming that the diodes do not breakdown in the reverse bias, the output voltage $V_{\rm O}$ (in volt) at the steady state is _____



Ans. (0)

During first positive quarter cycle both diodes D1 and D2 conduct and at $t = \frac{T}{4}$ both will be OFF.



Both the capacitors will charge to 10 V as shown is above figure and $V_0 = 0$ in steady state.

End of Solution

Consider the circuit shown in the figure. Assuming $V_{BE1} = V_{EB2} = 0.7$ volt, the **Q.14** value of the dc voltage V_{C2} (in volt) is _____.



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Ans. (0.5)

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$$\begin{split} Q_1: & V_{CB} = 0 \\ \text{We know} & V_{CB1} + V_{BE1} = V_{CE1} \\ \Rightarrow & V_{CE1} = V_{BE1} = 0.7 \text{ V} \\ \text{KVL to loop 1} \\ -2.5 + V_{CE1} + 0.7 + I_{B2} \times 10 \text{ K} + 1 \text{ V} = 0 \end{split}$$

$$I_{B2} = \frac{2.5 - 1.4 - 1}{10 K} = 0.01 \text{ mA}$$

$$\begin{split} I_{C2} &= \beta_2 \, I_{B2} \, {=} \, 0.5 \; \text{mA} \\ V_{C2} &= I_{C2} \times 1 \; K \, {=} \; 0.5 \times 10^{-3} \times 1 \times 10^3 \\ &= 0.5 \; \text{V} \end{split}$$

End of Solution

Q.15 In the astable multivibrator circuit shown in the figure, the frequency of oscillation (in kHz) at the output pin 3 is _____.



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Q.20 For the unity feedback control system shown in the figure, the open-loop transfer function G(s) is given as $G(s) = \frac{2}{s(s+1)}$ The steady state error e_{ss} due to a unit step input is G(s)► y(t) (b) 0.5 (a) 0 (d) ∞ (c) 1.0 Ans. (a) $E(s) = \frac{R(s)}{1 + G(s)H(s)}$ $R(s) = \frac{1}{s}; G(s) = \frac{2}{s(s+1)}; H(s) = 1$ $E(s) = \frac{\frac{1}{s}}{1 + \frac{2}{(s-1)}} = \frac{s+1}{s^2 + s + 2}$ $e_{ss} = Lt_{s \to 0} sE(s) = Lt_{s \to 0} \frac{s(s+1)}{s^2 + s + 2}$ $e_{ss} = 0$ End of Solution Q.21 For a superheterodyne receiver, the intermediate frequency is 15 MHz and the local oscillator frequency is 3.5 GHz. If the frequency of the received signal is greater than the local oscillator frequency, then the image frequency (in MHz) is _____. Ans. (3485) IF = 15 MHz $f_1 = 3.5 \, \text{GHz}$ $f_{\rm si}=f_l-{\rm IF}$ \Rightarrow = 3500 - 15 MHz = 3485 MHzEnd of Solution **Q**.22 An analog baseband signal, bandlimited to 100 Hz, is sampled at the Nyquist rate. The samples are quantized into four message symbols that occur independently with probabilities $p_1 = p_4 = 0.125$ and $p_2 = p_3$. The information rate (bits/sec) of the message source is _____.

Ans. (362.2)

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Q.23 A binary baseband digital communication system employs the signal

$$p(t) = egin{cases} rac{1}{\sqrt{T_s}}, 0 \leq t \leq T_s \ 0, & ext{otherwise} \end{cases}$$

for transmission of bits. The graphical representation of the matched filter output y(t) for this signal will be





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 $\frac{1}{\sqrt{T_s}} \longrightarrow t$ Impulse response of matched filter, $h(t) = P(T_s - t)$ $\frac{1}{\sqrt{T_s}} \xrightarrow{P(T_s - t) = h(t)}{1}$ $\frac{1}{\sqrt{T_s}} \longrightarrow t$ Output of matched filter, y(t) = P(t) * h(t)y(t) = P(t) + h(t)

P(t)



 $2T_s$

(d) horizontally polarized

Ans. (b)

Ans.

(c)

Left circularly polarized

- due to 180° phase difference between reflected and incident wave.
- due to direction change after the reflection from conductor.

• • End of Solution

- **Q.25** Faraday's law of electromagnetic induction is mathematically described by which one of the following equations?
 - (a) $\nabla \cdot \vec{B} = 0$ (b) $\nabla \cdot \vec{D} = \rho_v$ (c) $\nabla \times \vec{E} = -\frac{\partial \vec{B}}{\partial t}$ (d) $\nabla \times \vec{H} = \sigma \vec{E} + \frac{\partial \vec{D}}{\partial t}$

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Ans.	(c) Rate of change of magnetic field resul $ abla imes ec{E}$	ts in induced voltage = $-\frac{\partial \vec{B}}{\partial t}$	
	Two Marks C	• • • End of Solutions	ion
Q.26	The particular solution of the initial	value problem given below is	
	$\frac{d^2y}{dx^2} + 12\frac{dy}{dx} + 36y = 0 \text{ with } y(0) = 3 a$	and $\left. \frac{dy}{dx} \right _{x=0} = -36$	
	(a) $(3 - 18x)e^{-6x}$ (c) $(2 + 20x)e^{-6x}$	(b) $(3 + 25x)e^{-6x}$ (d) $(2 - 12x)e^{-6x}$	
Ans.	(a) $(D^{2} + 12 D + 36)^{4} = 0$ $(D + 6)^{2}y = 0$ $D = -6, -6$ $y = C_{1} + xC_{2})e^{-6x}$ $y = C_{1}e^{-6x} + C_{2}xe^{-6x}$ $y(0) = 3$ $y' = -6C_{1}e^{-6x} + C_{2}e^{-6x}$ $y'(0) = -36$ $-36 = -6C_{1} + C_{2}$ $-36 = -18 + C_{2}$ $y = 3e^{-6x} - 18 x e^{-6x}$ $y = (3 - 18x)e^{-6x}$	$3 = C_1 + 0 \implies C_1 = 3$ $-6x - 6C_2 x e^{-6x}$ $C_2 = -18$ End of Solution	ion
Q.27	If the vectors $e_1 = (1, 0, 2)$, $e_2 = (0, 1)$ basis of the three-dimensional real s can be expressed as (a) $u = -\frac{2}{5}e_1 - 3e_2 - \frac{11}{5}e_3$	(b) $u = -\frac{2}{5}e_1 - 3e_2 + \frac{11}{5}e_3$	nal R ³
	(c) $u = -\frac{2}{5}e_1 + 3e_2 + \frac{11}{5}e_3$	(d) $u = -\frac{2}{5}e_1 + 3e_2 - \frac{11}{5}e_3$	
Ans.	(d)		
	$\begin{bmatrix} 4\\ 3\\ -3 \end{bmatrix}$ $a - 2c$	$= a\begin{bmatrix}1\\0\\2\end{bmatrix} + b\begin{bmatrix}0\\1\\0\end{bmatrix} + c\begin{bmatrix}-2\\0\\1\end{bmatrix}$ $= 4$	

2a + c = -3



Q.28 A triangle in the *xy*-plane is bounded by the straight lines 2x = 3y, y = 0 and x = 3. The volume above the triangle and under the plane x + y + z = 6 is ______.

Ans. (10)

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Q.29 The values of the integral $\frac{1}{2\pi j} \oint_{c} \frac{e^{z}}{z-2} dz$ along a closed contour *c* in anti-clockwise

direction for

- (i) the point $z_0 = 2$ inside the contour c, and
- (ii) the point $z_0 = 2$ outside the contour *c*, respectively, are
- (a) (i) 2.72, (ii) 0 (b) (i) 7.39, (ii) 0
- (c) (i) 0, (ii) 2.72 (d) (i) 0, (ii) 7.39

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Ans.	(b) (i)	Z = 2 lies inside C
	(1)	$Z_0 = 2$ -nes inside C,
	SO	Res $f(z) = \lim_{z \to 2} (z - 2) \cdot \frac{e}{z - 2} = e^2 = 7.39$
		$\frac{1}{2\pi i} \int_{c} \frac{e^{z}}{z-2} dz = 2\pi i \cdot \frac{1}{2\pi i} (7.39) = 7.39$
	(ii)	$Z_0 = -2$ lies out side C then Res $f(z) = 0$
	SO	$\int_{c} \frac{e^{z}}{z-2} dz = 2\pi i \cdot \frac{1}{2\pi i} (0) = 0$
		• • • End of Solution
Q.30	A signal 2	$d\cos\left(\frac{2\pi}{3}t\right) - \cos(\pi t)$ is the input to an LTI system with the transfer
	function	
		$H(s) = e^s + e^{-s}$
	If C_k denote then c_k is	e the $k^{\rm m}$ coefficient in the exponential Fourier series of the output signal,
	(a) 0	(b) 1
	(c) 2	(d) 3
Ans.	(b)	
	Given,	$H(s) = e^{s} + e^{-s}$
		$H(e^{j\omega}) = e^{j\omega} + e^{-j\omega} = 2\cos\omega$
		$x(t)$ $H(e^{j\omega})$ $y(t)$
	If	$x(t) = 2\cos\left(\frac{2\pi}{3}t\right)$
		$\omega_0 = \frac{2\pi}{3}$
		$H(j\omega_0) = 2\cos\left(\frac{2\pi}{3}\right) = 2\left(-\frac{1}{2}\right) = -1$
		$y(t) = 2\cos\left(\frac{2\pi}{3}t + 180^\circ\right)$
		$x(t) = \cos \pi t$
	if	$x(t) = \cos \pi t$
		$\omega_0 = \pi$
		$H(e^{j\omega_0}) = 2\cos(\pi) = -2$

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$$y(t) = 2\cos(\pi t + 180^{\circ})$$

$$y(t) = 2\cos\left(\frac{2\pi}{3}t + \pi\right) - 2\cos(\pi t + \pi)$$

$$\omega_{1} = \frac{2\pi}{3}, \quad \omega_{2} = \pi$$

$$T_{1} = 3 \qquad T_{2} = 2$$

$$T_{0} = 6$$

$$\Rightarrow \qquad \omega_{0} = \frac{2\pi}{T_{0}} = \frac{\pi}{3}$$

$$y(t) = 2\cos(2\omega_{0}t + \pi) - 2\cos(3\omega_{0}t + \pi)$$

$$y(t) = e^{j(2\omega_{0}t + \pi)} + e^{-j(2\omega_{0}t + \pi)} - e^{-j(3\omega_{0}t + \pi)}$$

$$y(t) = -e^{j(2\omega_{0}t)} - e^{-j(2\omega_{0}t)} + e^{j(3\omega_{0}t)} + e^{-j(3\omega_{0}t)}$$

$$\therefore \qquad C_{3} = 1$$
End of Solution

Q.31 The ROC (region of convergence) of the z-transform of a discrete-time signal is represented by the shaded region in the z-plane. If the signal

 $x[n] = (2.0)^{|n|}, -\infty < n < +\infty$, then the ROC of its z-transform is represented by





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z-plane

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Re



(d)



Q.32 Assume that the circuit in the figure has reached the steady state before time t = 0 when the 3 Ω resistor suddenly burns out, resulting in an open circuit. The current i(t) (in ampere) at $t = 0^+$ is _____.



Ans. (-1)

at $t = 0^{-}$



$$V_{3F} = 10 \times \frac{2}{5} = 4 \text{ V}$$

 $V_{2F} = 10 \times \frac{3}{5} = 6 \text{ V}$

at $t = 0^+$



• • End of Solution

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 $\frac{V_1}{1} + \frac{V_1 - 8}{1} + \frac{V_1 - 8}{1} + \frac{V_1}{1} = 0$ or $V_1 = 4$ V considering KVL, we get

Using KCL at V_1



 1Ω

• • • End of Solution





Ans.

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(a) Redrawing the circuit 6Ω $Z_{11} = \frac{V_1}{I_1} = 3 \| 6 = 2 \Omega$ $V_2 = -3 \times I_{3\Omega} = -3 \times I_1 \times \frac{6}{9} = -2I_1$ $Z_{21} = \frac{V_2}{I_1} = -2$ *.*.. $Z_{22} = \left. \frac{V_2}{I_2} \right|_{I_1 = 0} = 3 \left\| 6 = 2 \, \Omega \right.$ now, $I_1 = 0$ $N_{6\Omega}^{N}$ $V_1 = -6 \times I_{6\,\Omega} = -6 \times I_2 \times \frac{3}{9} = -2$

 $[Z] = \begin{bmatrix} 2 & -2 \\ -2 & 2 \end{bmatrix}$

...

• • • End of Solution

Q.35 A continuous-time speech signal $x_a(t)$ is sampled at a rate of 8 kHz and the samples are subsequently grouped in blocks, each of size N. The DFT of each block is to be computed in real time using the radix-2 decimation-in-frequency FFT algorithm. If the processor performs all operations sequentially, and takes 20 µs for computing each complex multiplication (including multiplications by 1 and -1) and the time required for addition/subtraction is negligible, then the maximum value of N is _____.

Ans. (4096)

 \Rightarrow

$$f_s = 8000 \text{ samples/sec}$$

$$T_s = \frac{1}{f_s} = \frac{1}{8000} \text{ sec.}$$

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Time for each multiplication = $T_m = 20 \mu \text{sec.}$ $T_m = 20 \times 10^{-6} \text{sec}$ Suppose block is of size N, then time taken to generate each

block = $N \times T_s = N \times \frac{1}{8000}$. No. of multiplications that can be performed by

processor in the time taken for each block = $\frac{N \times T_s}{T_m}$

No. of multiplications required to compute DFT by Radix - 2 FFT algorithm

$$= \frac{N}{2}\log_2 N$$

No. of multiplication required by $FFT \le No.$ of multiplications that can be performed by the processor in the time taken in each block

[Reason : real time]

 \Rightarrow

$$\begin{split} \frac{N}{2} \log_2 N &\leq \frac{N \times T_s}{T_m} \\ \log_2 N &\leq \frac{2 \times \frac{1}{8000}}{20 \times 10^{-6}} = 12.5 \\ N &\leq 2^{12.5} \\ N &\leq 2^{12} = 4096 \end{split}$$

End of Solution

Q.36 The direct form structure of an FIR (finite impulse response) filter is shown in the figure.



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Ans. (c)

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y[n] = 5[x[n] - x[n-2]] $H(z) = \frac{Y(z)}{X(z)} = 5[1 - z^{-2}]$ But, $z = e^{j\omega}$ $H(e^{j\omega}) = 5[1 - e^{-j2\omega}]$ $0 = 0 \qquad |H(e^{j\omega})| = 0$ $\omega = \frac{\pi}{2} \qquad |H(e^{j\omega})| = 10$ $\omega = \pi \qquad |H(e^{j\omega})| = 0$ $\omega = \pi \qquad |H(e^{j\omega})| = 0$ $M = \pi \qquad |H(e^{j\omega})| = 0$

End of Solution

Q.37 The injected excess electron concentration profile in the base region of an *npn* BJT, biased in the active region, is linear, as shown in the figure. If the area of the emitter-base junction is 0.001 cm^2 , $\mu_n = 800 \text{ cm}^2/(\text{V-s})$ in the base region and depletion layer widths are negligible, then the collector current I_C (in mA) at room temperature is

(Given: thermal voltage V_T = 26 mV at room temperature, electronic charge q = 1.6 \times 10^{-19}C)



Ans. (6.656)

$$\begin{split} I_c &= AqD_n \; \frac{dn}{dx} \; \text{where} \; D_n = \mu_n V_T \\ &= 0.001 \; (1.6 \times 10^{-19}) \; 800 \times 26 \times 10^{-3} \left[\frac{10^{14}}{0.5 \times 10^{-4}} \right] \\ &= 66.56 \times 10^{-4} \, \text{A} = 6.656 \; \text{mA} \end{split}$$

End of Solution

Q.38 Figures I and II show two MOS capacitors of unit area. The capacitor in Figure I has insulator materials X (of thickness $t_1 = 1$ nm and dielectric constant $\varepsilon_1 = 4$) and Y (of thickness $t_2 = 3$ nm and dielectric constant $\varepsilon_2 = 20$). The capacitor in Figure II has only insulator material X of thickness t_{Eq} . If the capacitors are of equal capacitance, then the value of t_{Eq} (in nm) is _____.



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Ans. (1.6)

From the figure I Both the capacitors C_1 and C_2 are in series

Total Capacitance

$$C = \frac{C_1 C_2}{C_1 + C_2}$$

$$C = \frac{\frac{A\varepsilon_1}{t_1} \cdot \frac{A\varepsilon_2}{t_2}}{\frac{A\varepsilon_1}{t_1} + \frac{A\varepsilon_2}{t_2}} = \frac{\frac{A \times 4}{10^{-9}} \cdot \frac{A \times 20}{3 \times 10^{-9}}}{\frac{A \times 4}{10^{-9}} + \frac{A \times 20}{3 \times 10^{-9}}}$$

$$C = 2.5 \times 10^9 \times A$$

From figure II

...

$$C = \frac{\varepsilon A}{t_{eq}}$$

Since both capacitors must be equal in figures I and II

$$2.5 \times 10^9 \times A = \frac{A \times 4}{t_{eq}}$$

 $t_{eq} = 1.6 \text{ nm}$

• End of Solution

Q.39 The I-V characteristics of the zener diodes *D*1 and *D*2 are shown in Figure I. These diodes are used in the circuit given in Figure II. If the supply voltage is varied from 0 to 100 V, then breakdown occurs in







Q.41 In the circuit shown in the figure, the channel length modulation of all transistors is non-zero ($\lambda \neq 0$). Also, all transistors operate in saturation and have negligible body effect. The ac small signal voltage gain (V_0/V_{in}) of the circuit is



Ans.







Node equation at P_1 : $g_{m1}V_{gs1} + \frac{V_0}{r_{01}} + \frac{V_0}{r_{02}} + \frac{V_0}{r_{02}} - g_{m_2}V_{gs_2} = 0$ $V_0\left(\frac{1}{r_{01}} + \frac{1}{r_{02}} + g_{m2} + \frac{1}{r_{03}}\right) = -g_{m1}V_{in}$ $\Rightarrow \qquad A_v = \frac{V_0}{V_{in}} = -g_{m1}\left[r_{01} \parallel \left[r_{02} \parallel \frac{1}{g_{m2}}\right] \parallel r_{03}\right]$ End of Solution

Q.42 In the circuit shown in the figure, transistor M1 is in saturation and has transconductance $g_m = 0.01$ siemens. Ignoring internal parasitic capacitances and assuming the channel length modulation λ to be zero, the small signal input pole frequency (in kHz) is _____.





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Taking miller's equivalent and assume $r_0 = \infty$





GATE-2016 Exam Solutions ES, GATE & PSUs Electronics Engg. (Session-4, 5)



Ans.

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(d) s^3 1 (2K + 3) s^2 2K4 $\frac{4K^2 + 6K - 4}{2K}$ 0 s s° 4 K > 0For stability, ...(i) $4 K^2 + 6 K - 4 > 0$ $2K^2 + 3K - 2 > 0$ (2K-1)(K+2) > 0 $K > \frac{1}{2}$ or, K < -2...(ii) \Rightarrow $0.5 < K < \infty$ Hence,

Q.47 A second-order linear time-invariant system is described by the following state equations

$$\frac{d}{dt}x_1(t) + 2x_1(t) = 3u(t)$$
$$\frac{d}{dt}x_2(t) + x_2(t) = u(t)$$

where $x_1(t)$ and $x_2(t)$ are the two state variables and u(t) denotes the input. If the output $c(t) = x_1(t)$, then the system is

(a) controllable but not observable

(b) observable but not controllable

- (c) both controllable and observable
- (d) neither controllable nor observable

Ans. (a)

$$\begin{aligned} \dot{x}_{1}(t) + 2x_{1}(t) &= 3u(t) \\ \dot{x}_{2}(t) + x_{2}(t) &= u(t) \\ \dot{x}_{1}(t) &= -2x_{1}(t) + 3u(t) \\ \dot{x}_{2}(t) &= -x_{2}(t) + u(t) \\ \begin{bmatrix} \dot{x}_{1} \\ \dot{x}_{2} \end{bmatrix} &= \begin{bmatrix} -2 & 0 \\ 0 & -1 \end{bmatrix} \begin{bmatrix} x_{1} \\ x_{2} \end{bmatrix} + \begin{bmatrix} 3 \\ 1 \end{bmatrix} U \\ c(t) &= x_{1}(t) \\ &= \begin{bmatrix} 1 & 0 \end{bmatrix} \begin{bmatrix} x_{1} \\ x_{2} \end{bmatrix} \\ A &= \begin{bmatrix} -2 & 0 \\ 0 & -1 \end{bmatrix}; \quad B = \begin{bmatrix} 3 \\ 1 \end{bmatrix}; \quad C = \begin{bmatrix} 1 & 0 \end{bmatrix} \end{aligned}$$

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End of Solution



For controllability

$$Q_C = \begin{bmatrix} B & AB \end{bmatrix} = \begin{bmatrix} 3 & -6\\ 1 & -1 \end{bmatrix}$$

 $|Q_C| \neq 0 \rightarrow$ Hence system is controllable.

For observability

$$\begin{split} Q_0 &= \begin{bmatrix} C \\ CA \end{bmatrix} = \begin{bmatrix} 1 & 0 \\ -2 & 0 \end{bmatrix} \\ Q_0 &\mid = 0 & \longrightarrow \text{ Hence system is not observable} \end{split}$$

Q.48 The forward-path transfer function and the feedback-path transfer function of a single loop negative feedback control system are given as

$$G(s) = \frac{K(s+2)}{s^2 + 2s + 2}$$
 and $H(s) = 1$,

respectively. If the variable parameter K is real positive, then the location of the breakaway point on the root locus diagram of the system is _____.

Ans. (-3.41)

$$G(s) = \frac{K(s+2)}{s^2 + 2s + 2}; H(s) = 1$$

1+G(s)H(s) = 0

$$1 + \frac{K}{(s^2) + 2s + 2}(s+2) = 0$$

$$K = -\frac{(s^2 + 2s + 2)}{(s+2)}$$



$$\frac{dK}{ds} = -\left(\frac{(2s+2)(s+2) - (s^2 + 2s + 2)}{(s+2)^2}\right)$$

For break away points, $\frac{dK}{ds} = 0$ (2s + 2) (s + 2) - (s² + 2s + 2) = 0 2s² + 6s + 4 - s² - 2s - 2 = 0 s² + 4s + 2 = 0 End of Solution

$$s = \frac{-4 \pm \sqrt{16 - 8}}{2}$$
$$= \frac{-4 \pm 2\sqrt{2}}{2} = -2 \pm \sqrt{2}$$
$$s = -0.58 ; s = -3.41$$
But,
$$s = -3.41 \text{ lies on root locus}$$
Hence
$$s = -3.41$$

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Q.49 A wide sense stationary random process X(t) passes through the LTI system shown in the figure. If the autocorrelation function of X(t) is $R_X(\tau)$, then the autocorrelation function $R_Y(\tau)$ of the output Y(t) is equal to



Q.50 A voice-grade AWGN (additive white Gaussian noise) telephone channel has a bandwidth of 4.0 kHz and two-sided noise power spectral density $\frac{\eta}{2} = 2.5 \times 10^{-5}$ Watt per Hz. If information at the rate of 52 kbps is to be transmitted over this channel with arbitrarily small bit error rate, then the minimum bit-energy E_b (in mJ/bit) necessary is _____.

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End of Solution

Ans. (31.5)

$$C = B \log_2 \left(1 + \frac{S}{N} \right)$$

$$S = E_b \cdot R_b \qquad (E_b = \text{bit energy}, R_b = \text{information rate bits/sec})$$

$$C = B \log_2 \left(1 + \frac{E_b R_b}{N_o B} \right)$$

For distortionless transmission, C should be atleast of R_b

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$$\frac{R_b}{B} = \log_2 \left(1 + \frac{E_b R_b}{N_o B} \right)$$

$$E_b = (2^{Rb/B} - 1) \frac{N_o B}{R_b}$$

$$= \frac{(2^{52/13} - 1) \times 2 \times 2.5 \times 10^{-5} \times 4}{52}$$

$$E_b \approx 31.504 \text{ mJ/bit}$$

End of Solution

Q.51 The bit error probability of a memoryless binary symmetric channel is 10^{-5} . If 10^5 bits are sent over this channel, then the probability that not more than one bit will be in error is _____.

Ans. (0.7357)

bit error probability, $p = 10^{-5}$ Number of bits transmitted,

 $n = 10^5$

If n-bits are transmitted, probability of getting error in 'r' bits is given by

$$p_e = {}^nC_r p^r (1-p)^{n-r}$$

The probability that not more than one bit will be in crror is

$$= {}^{n}C_{0}p^{0}(1-p)^{n-0} + {}^{n}C_{1}(p)^{1}(1-p)^{n-1}$$

= $(1-p)^{n} + np(1-p)^{n-1}$
= $(1-10^{-5})^{10^{5}} + 10^{5} \times 10^{-5}(1-10^{-5})^{10^{5}-1}$
= 0.7357

End of Solution

Q.52 Consider an air-filled rectangular waveguide with dimensions a = 2.286 cm and b = 1.016 cm. At 10 GHz operating frequency, the value of the propagation constant (per meter) of the corresponding propagating mode is ______.

Ans. (158)

Operation frequency $= 10 \,\text{GHz}$



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Cut off frequency for
$$TE_{10}$$
 $f_c = \frac{c}{2a}$
 $f_c = \frac{3 \times 10^8}{2 \times 2.286 \times 10^{-2}} = 6.57 \text{ GHz}$
Next mode TE_{20} has $f_c = 13 \text{ GHz}$
10 GHz operates only in dominant mode.
 $\overline{\gamma} = \sqrt{\left(\frac{m\pi}{a}\right)^2 - \frac{a^2\mu}{(3 \times 10^8)^2}}$
 $= \sqrt{\left(\frac{\pi}{a}\right)^2 - \frac{(2\pi f)^2}{(3 \times 10^8)^2}}$
 $= \pi \sqrt{\left(\frac{1}{2.286 \times 10^{-2}}\right)^2 - \left(\frac{2 \times 10 \times 10^9}{3 \times 10^8}\right)^2}$
 $= j158 \text{ (m}^{-1)}$
Q.53 Consider an air-filled rectangular waveguide with dimensions $a = 2.286 \text{ cm}$ and $b = 1.016 \text{ cm}$. The increasing order of the cut-off frequencies for different modes is
(a) $TE_{01} < TE_{10} < TE_{11} < TE_{20}$ (b) $TE_{20} < TE_{11} < TE_{10} < TE_{01}$
(c) $TE_{10} < TE_{10} < TE_{11}$ (d) $TE_{10} < TE_{11} < TE_{20} < TE_{01}$
Ans. (c)
 $a = 2.286 \text{ cm}$
 $b = 1.016 \text{ cm}$
 $f_{c_{TE_{20}}} = \frac{c}{2a}$; $f_{c_{TE_{01}}} = \frac{c}{2b}$
 $f_{c_{TE_{20}}} = \frac{c}{a}$; $f_{c_{TE_{01}}} = \frac{c}{2b}$
 $f_{c_{TE_{20}}} < f_{c_{TE_{20}}} < f_{c_{TE_{20}}} < f_{c_{TE_{11}}}$
As $a > 2b \Rightarrow f_{c_{TE_{20}}} < f_{c_{TE_{20}}} < f_{c_{TE_{21}}} < f_{c_{TE_{11}}}$
Q.54 A radar operating at 5 GHz uses a common antenna for transmission and reception. The antenna has a gain of 150 and is aligned for maximum directional radiation and reception a tarreet 1 km away having radar cross-section of 3 m^2.

Ans. (0.012)

f=5 GHz, G=150, R=1 km, $P_t=100$ kW, $\sigma=3$ m^2

If it transmits 100 kW, then the received power (in μ W) is _____



$$\begin{split} P_r &= \frac{(G\lambda)^2 \cdot \sigma}{(4\pi)^3 R^4} \times P_t \\ &= \frac{\left(150 \times \frac{3 \times 10^8}{5 \times 10^9}\right)^2 \cdot 3}{(4\pi)^3 \cdot 10^{12}} \times 10^5 = \frac{81 \times 3 \times 10^5}{(4\pi)^3 \times 10^{12}} \\ &= 1.224 \times 10^{-8} = 0.012 \ \mu \text{W} \end{split}$$

Q.55 Consider the charge profile shown in the figure. The resultant potential distribution is best described by

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